

Product specification Supersedes data of 1997 Jul 15 IC24 Data Handbook

1998 Jun 23



Philips Semiconductors

74LV4052

FEATURES

- Optimized for low voltage applications: 1.0 to 6.0 V
- \bullet Accepts TTL input levels between V_{CC} = 2.7 V and V_{CC} = 3.6 V
- Low typ "ON" resistance:
- Logic level translation: to enable 3 V logic to communicate with ± 3 V analog signals
- Typical "break before make" built in
- Analog/Digital multiplexing and demultiplexing
- Signal gating
- Output capability: non-standard
- I_{CC} category: MSI

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5$ ns

DESCRIPTION

The 74LV4052 is a low-voltage CMOS device and is pin and function compatible with the 74HC/HCT4052.

The 74LV4052 is a dual 4-channel analog multiplexer/demultiplexer with a common select logic. Each multiplexer has four independent inputs/outputs (nY $_0$ to nY $_3$) and a common input/output (nZ). The common channel select logics include two digital select inputs (S0 and S_1) and an active LOW enable input (\overline{E}).

With E LOW, one of the four switches is selected (low impedance ON-state) by S_0 and S_1 . With \overline{E} HIGH, all switches are in the high impedance OFF-state, independent of S_0 and $S_1.\ V_{CC}$ and GND are the supply voltage pins for the digital control inputs (S_0 , S_1 and \overline{E}). The V_{CC} to GND ranges are 1.0 to 6.0 V. The analog inputs/outputs (nY₀, to nY₃, and nZ) can swing between V_{CC} as a positive limit and V_{EE} as a negative limit. V_{CC} - V_{EE} may not exceed 6.0 V. For operation as a digital multiplexer/demultiplexer, V_{EE} is connected to GND (typically ground).

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT	
t _{PZH} /t _{PZL}	Turn "ON" time Ē or V _{OS} S _n	$C_L = 15 \text{ pF}$ $R_L = 1K\Omega$	30		
t _{PHZ} /t _{PLZ}	Turn "OFF" time Ē or V _{OS} S _n	$V_{CC} = 3.3 V$	22	ns	
Cl	Input capacitance		3.5		
C _{PD}	Power dissipation capacitance per switch	See Notes 1 and 2	57	pF	
C _S Maximum switch capacitance independent (Y) common (Z)			5 12	P.	

NOTES:

 C_{PD} is used to determine the dynamic power dissipation (P_D in μW) 1.

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum ((C_L + C_S) \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz; C_L = output load capacity in pF;

fo = output frequency in MHz; C_S = maximum switch capacitance in pF;

 V_{CC} = supply voltage in V; $\sum ((C_L + C_S) \times V_{CC}^2 \times f_0)$ = sum of the outputs.

2. The condition is $V_I = GND$ to V_{CC} .

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	Code
16-Pin Plastic DIL	-40°C to +125°C	74LV4052 N	74LV4052 N	SOT38-4
16-Pin Plastic SO	-40°C to +125°C	74LV4052 D	74LV4052 D	SOT109-1
16-Pin Plastic SSOP Type II	-40°C to +125°C	74LV4052 DB	74LV4052 DB	SOT338-1
16-Pin Plastic TSSOP Type I	-40°C to +125°C	74LV4052 PW	74LV4052PW DH	SOT403-1

PIN CONFIGURATION

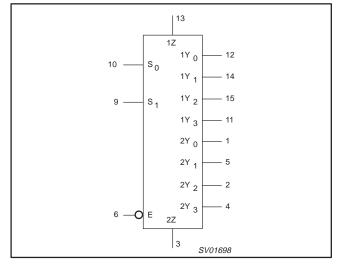
2Y ₀ 1		16 V _{CC}
2Y ₂ 2		15 1Y ₂
2Z 3		14 1Y ₁
2Y ₃ 4		13 1Z
2Y ₁ 5		12 1Y ₀
E 6		11 1Y ₃
V _{EE} 7		10 S ₀
GND 8		9 S ₁
	SV	/01697

PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION	
1, 5, 2, 4	2Y ₀ , 2Y ₃	Independent inputs/outputs	
6	Ē	Enable input (active LOW)	
7	V _{EE}	Negative supply voltage	
8	GND	Ground (0 V)	
10, 9	S ₀ , S ₁	Select inputs	
12, 14, 15, 11	$1Y_0$ to $1Y_3$	Independent inputs/outputs	
13, 3	1Z, 2Z	Common inputs/outputs	
16	V _{CC}	Positive supply voltage	

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LOGIC SYMBOL



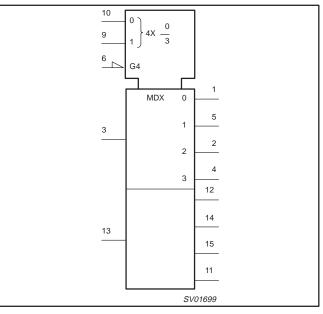
FUNCTION TABLE

	INPUTS						
Ē	S ₁	ON					
L	L	L	nY ₀ – nZ nY ₁ – nZ				
L	L	н	nY ₁ – nZ				
L	Н	L	$nY_2 - nZ$				
L	Н	Н	nY ₃ – nZ				
Н	Х	Х	None				

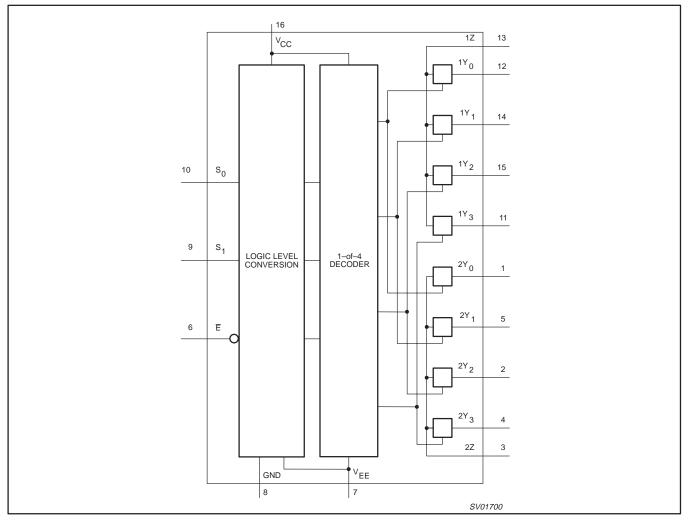
NOTES:

1. H = HIGH voltage level 2. L = LOW voltage level 3. X = don't care

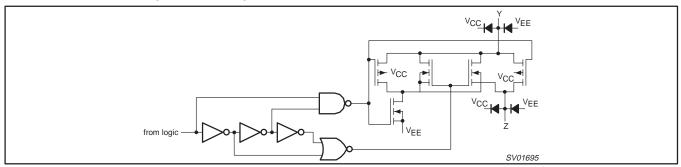
LOGIC SYMBOL (IEEE/IEC)



FUNCTIONAL DIAGRAM



SCHEMATIC DIAGRAM (ONE SWITCH)



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Product specification

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ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0 V).

SYMBOL	DL PARAMETER CONDITIONS		RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
$\pm I_{IK}$	DC input diode current	$V_{\rm I}$ < -0.5 or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	20	mA
$\pm I_{SK}$	DC switch diode current	$V_{\rm S}$ < -0.5 or $V_{\rm S}$ > $V_{\rm CC}$ + 0.5 V	20	mA
$\pm I_{S}$	DC switch current	$-0.5 \text{ V} < \text{V}_{\text{S}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	25	mA
T _{stg}	Storage temperature range		-65 to +150	°C
Power dissipation per package – plastic DIL – plastic mini-pack (SO)		for temperature range: -40 to +125°C above +70°C derate linearly with 12 mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V _{CC}	DC supply voltage	See Note 1 and Figure 5	1.0	3.3	6.0	V
VI	Input voltage		0	-	V _{CC}	V
Vo	Output voltage		0	-	V _{CC}	V
T _{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C
t _r , t _f	Input rise and fall times	$V_{CC} = 1.0 V \text{ to } 2.0 V$ $V_{CC} = 2.0 V \text{ to } 2.7 V$ $V_{CC} = 2.7 V \text{ to } 6.0 V$	- - -	- - -	500 200 100	ns/V

NOTE:

1. The LV is guaranteed to function down to V_{CC} = 1.0V (input levels GND or V_{CC}); DC characteristics are guaranteed from V_{CC} = 1.2V to V_{CC} = 6.0V.

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, voltages are referenced to GND (ground = 0 V)

				LIMITS						
SYMBOL	PARAMETER	TEST CO	NDITIONS	-4	0°C to +8	5°C	-40°C to +125°C		UNIT	
				MIN	TYP ¹	MAX	MIN	MAX	1	
		V _{CC} = 1.2 V		0.9			0.9			
		V _{CC} = 2.0 V		1.4			1.4		1	
VIH	HIGH level Input voltage	V _{CC} = 2.7 to 3.6 V		2.0			2.0		V	
	Vollage	V _{CC} = 4.5 V		3.15			3.15		1	
		V _{CC} = 6.0 V		4.20			4.20		1	
		V _{CC} = 1.2 V				0.3		0.3		
		V _{CC} = 2.0 V				0.6		0.6	1	
V _{IL}	LOW level Input voltage	V _{CC} = 2.7 to 3.6 V				0.8		0.8	V	
	Voltage	V _{CC} = 4.5 V				1.35		1.35	1	
		V _{CC} = 6.0 V				1.80		1.80	1	
	Input leakage	V _{CC} = 3.6				1.0		1.0		
±II	current	$V_{\rm CC} = 6.0$	$V_{I} = V_{CC} \text{ or GND}$			2.0		2.0	- μΑ	
	Analog switch	V _{CC} = 3.6	$V_{I} = V_{IH} \text{ or } V_{IL}$			1.0		1.0		
±ls	OFF-state current per channel	V _{CC} = 6.0	$IV_SI = V_{CC} - GND$ (See Figure 2)			2.0		2.0	μΑ	
	Analog switch	V _{CC} = 3.6	$V_{I} = V_{IH} \text{ or } V_{IL}$			1.0		1.0		
	ON-state current	V _{CC} = 6.0	IV _S I = V _{CC} - GND (See Figure 3)			2.0		2.0	- μΑ	
	Quiescent supply	00	$V_I = V_{CC}$ or GND;			20.0		40		
Icc	current	V _{CC} = 6.0 V	$V_{IS} = GND \text{ or } V_{CC};$ $V_{OS} = V_{CC} \text{ or } GND$			40.0		80	- μΑ	
ΔI_{CC}	Additional quiescent supply current per input	$V_{CC} = 2.7 \text{ to } 3.6 \text{ V}$	$V_{I} = V_{CC} - 0.6 V$			500		850	μA	
		V _{CC} = 1.2 V								
	ON-resistance	V _{CC} = 2.0 V			145	325		375	1	
R _{ON}	(peak)	V _{CC} = 2.7 V	$V_I = V_{IH} \text{ or } V_{IL};$		90	200		235	Ω	
		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$	I _S = 1000 μA;		80	180		210	1	
		V _{CC} = 4.5 V	V _{IS =} V _{CC} to GND		60	135		160	1	
		V _{CC} = 6.0 V	1		55	125		145	1	
		V _{CC} = 1.2 V			225					
	ON-resistance	V _{CC} = 2.0 V			110	235		270	1	
R _{ON}	(rail)	V _{CC} = 2.7 V	$V_{I} = V_{IH} \text{ or } V_{IL}$		70	145		165	Ω	
		V_{CC} = 3.0 to 3.6 V	I _S = 1000 _μ A;		60	130		150		
		V _{CC} = 4.5 V	V _{IS =} GND		45	100		115	1	
		V _{CC} = 6.0 V	1 1		40	85		100	1	

NOTES:
1. All typical values are measured at T_{amb} = 25°C.
2. At supply voltages approaching 1.2 V, the analog switch ON-resistance becomes extremely non-linear. Therefore, it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.
3. R_{ON} (MAX) data is preliminary.

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						LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS		-40°C to +85°C			-40°C t	o +125°C	
				MIN	TYP ¹	MAX	MIN	MAX	1
		V _{CC} = 1.2 V	$V_{I} = V_{IH} \text{ or } V_{IL};$ $I_{S} = 100 \ _{\mu}A;$ $V_{IS} = V_{CC}$		250				Ω
	ON-resistance	V _{CC} = 2.0 V			120	320		370	
R _{ON}	(rail)	V _{CC} = 2.7 V	$V_I = V_{IH} \text{ or } V_{IL};$		75	195		225	1 '
		V _{CC} = 3.0 to 3.6 V	$I_{S} = 1000 \mu A;$ $V_{IS} = V_{CC}$		70	175		205	Ω
		V _{CC} = 4.5 V	$V_{IS} = V_{CC}$		50	130		150	1
		V _{CC} = 6.0 V	1		45	120		135	1
		V _{CC} = 1.2 V							
	Maximum variation	V _{CC} = 2.0 V	1		5				1
ΔR _{ON}	of ON-resistance	V _{CC} = 2.7 V	$V_{I} = V_{IH} \text{ or } V_{IL}$		4				\Box_{Ω}
	between any two	V _{CC} = 3.0 to 3.6 V	$V_{IS} = V_{CC}$ to GND		4				
	channels	V _{CC} = 4.5 V	1		3				1
		V _{CC} = 6.0 V	1		2		1		1

NOTES:

All typical values are measured at T_{amb} = 25°C.
 At supply voltages approaching 1.2 V, the analog switch ON-resistance becomes extremely non-linear. Therefore, it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.

3. R_{ON} (MAX) data is preliminary.

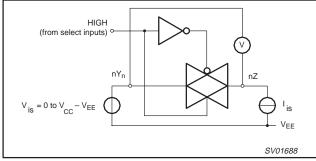


Figure 1. Test circuit for measuring ON-resistance (R_{ON}).

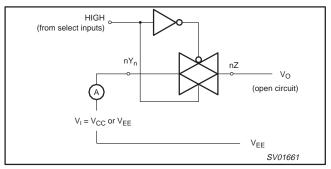


Figure 3. Test circuit for measuring ON-state current.

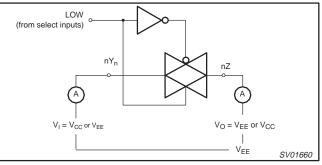


Figure 2. Test circuit for measuring OFF-state current.

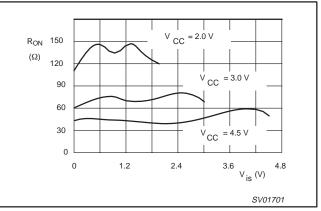


Figure 4. Typical ON-resistance (Ron) as a function of input voltage (V_{is}) for $V_{is} = 0$ to $V_{CC} - V_{EE}$.

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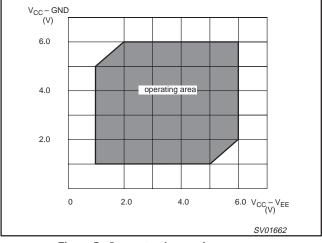


Figure 5. Guaranteed operating area as a function of the supply voltages.

AC CHARACTERISTICS

GND = 0 V; $t_r = t_f \le 2.5ns$; C_L = 50pF

		CONDIT	ON						
SYMBOL	PARAMETER	CONDITI	–40 to +85 °C			–40 to +125 °C		UNIT	
		V _{CC} (V)	OTHER	MIN	TYP ¹	МАХ	MIN	МАХ	
		1.2			25				
		2.0	R _L = ∞;		9	17		20	
t	Propagation delay	2.7	$C_{L} = 50 \text{ pF}$		6	13		15	ns
t _{PHL} /t _{PLH}	V _{is} to V _{os}	3.0 to 3.6	Figure 12		5 ²	10		12	115
		4.5	Figure 12		4	9		10	-
		6.0			3	7		8	
		1.2			190				ns
		2.0	$R_L = 1k\Omega;$		65	121		146	
t/t	Turn-on time	2.7	$C_{L} = 50 \text{pF}$		48	89		108	
t _{PZH} /t _{PZL}	Ē, S _n to V _{OS}	3.0 to 3.6	Figures 13		36 ²	71		86	
		4.5	and 1		32	60		73	
		6.0			25	46		56	
		1.2			125				
		2.0	$R_L = 1k\Omega$:		43	80		95	ns
t _{PHZ} /t _{PLZ}	Turn-off time	2.7	$C_L = 50 \text{pF}$		33	59		71	
'PHZ/'PLZ	Ē, Sn to V _{OS}	3.0 to 3.6	Figures 13		26 ²	48		57	
		4.5	and 1		23	41		49	
		6.0			18	32		38	

NOTES:

1. Unless otherwise stated, all typical values are measured at $T_{amb} = 25^{\circ}C$ 2. Typical values are measured at $V_{CC} = 3.3 V$.

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ADDITIONAL AC CHARACTERISTICS

Recommended conditions and typical values

GND = 0 V; $t_r = t_f \le 2.5$ ns

SYMBOL	PARAMETER	TYP.	UNIT	V _{CC} (V)	V _{is(p-p)} (V)	CONDITIONS
	Sine-wave distortion f = 1 kHz	0.80 0.40	%	3.0 6.0	2.75 5.50	$R_L = 10 k\Omega$; $C_L = 50 pf$ Figure 9 and 10
	Sine-wave distortion f = 10 kHz	2.40 1.20	%	3.0 6.0	2.75 5.50	$R_L = 10 k\Omega; C_L = 50 pf$ Figure 9 and 10
	Switch "OFF" signal feed through	-50 -50	dB	3.0 6.0	Note 1	$R_L = 600 \Omega$; $C_L = 50 pf$; f= 1 MHz Figures 5 and 11
	Crosstalk between any two switches/multiplexers	-60 -60	dB	3.0 6.0	Note 1	$R_L = 600 \Omega$; $C_L = 50 pf$; f= 1 MHz Figure 8
V _(p-p)	Crosstalk voltage between enable or address input to any switch (peak-to-peak value)	110 120	mV	3.0 6.0		$R_L = 600 \Omega$; $C_L = 50 pf$; f= 1 MHz (S _n or Ē, square wave between V _{CC} and GND t _r = t _f = 6 ns) Figure 8
f _{max}	Minimum frequency response (–3 dB)	180 200	MHz	3.0 6.0	Note 2	$R_L = 50 \Omega$; $C_L = 50 pF$ Figures 6, 8 and 9
CS	Maximum switch capacitance	5	pf			

GENERAL NOTES:

1. V_{is} is the input voltage at nY or nZ terminal, whichever is assigned as an input.

2. V_{OS} is the output voltage at nY or nZ terminal, whichever is assigned as an output.

NOTES:

1. Adjust input voltage V_{is} is 0 dBm level (0 dBm = 1 mW into 600 Ω).

2. Adjust input voltage V_{is} is 0 dBm level at V_{OS} for 1 MHz (0 dBm = 1 mW into 50 Ω).

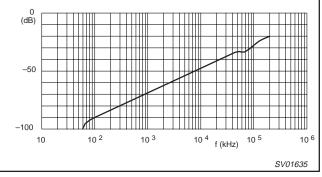


Figure 6. Typical switch "OFF" signal feed-through as a function of frequency.

NOTES TO FIGURES 6 AND 7:

Test conditions: V_{CC} = 3.0 V; GND = 0 V; V_{EE} = -3.0 V; R_L = 50 Ω ; R_{SOURCE} = 1k Ω .

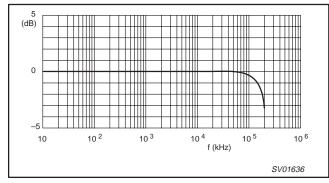


Figure 7. Typical frequency response.

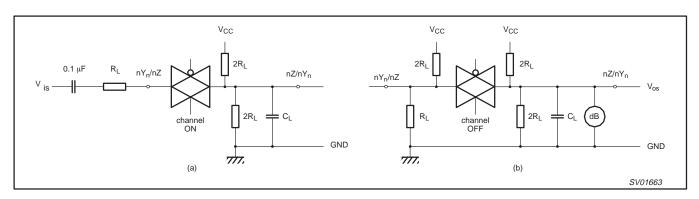
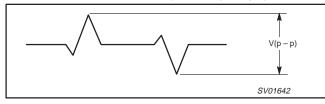


Figure 8. Test circuit for measuring crosstalk between any two switches. (a) channel ON condition; (b) channel OFF condition.

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NOTE TO FIGURE 8:

The crosstalk is defined as follows (oscilloscope output):



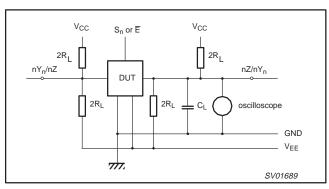


Figure 9. Test circuit for measuring crosstalk between control and any switch.

NOTE TO FIGURE 9:

Adjust input voltage to obtain 0 dBm at V_{OS} when F_{in} = 1 MHz. After set-up frequency of f_{in} is increased to obtain a reading of –3 dB at V_{OS}.

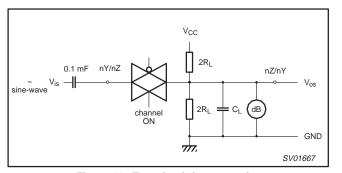
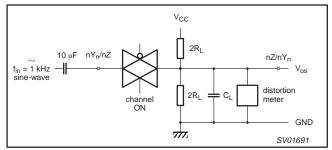
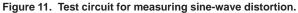


Figure 10. Test circuit for measuring minimum frequency response.





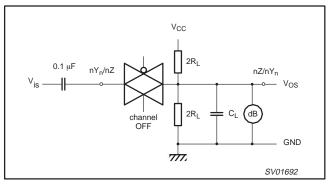


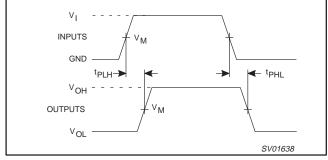
Figure 12. Test circuit for measuring switch "OFF" signal feed-through.

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WAVEFORMS

NOTES:

- 1.
- V_{OL}^{M} and V_{OH} are the typical output voltage drop that occur with 2. the output load
- 3. $V_x = V_{OL} + 0.3 V \text{ at } 2.7 V \le V_{CC} \le 3.6 V$ $V_x = V_{OL} + 0.1 \times V_{CC} \text{ at } 2.7 V > V_{CC} > 3.6 V$ $V_Y = V_{OH} 0.3 V \text{ at } 2.7 V \le V_{CC} \le 3.6 V$ $V_Y = V_{OH} 0.1 \times V_{CC} \text{ at } 2.7 V > V_{CC} > 3.6 V$





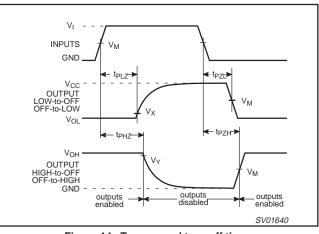


Figure 14. Turn-on and turn-off times for the inputs (S_n, \overline{E}) to the output (V_{os}) .

TEST CIRCUIT

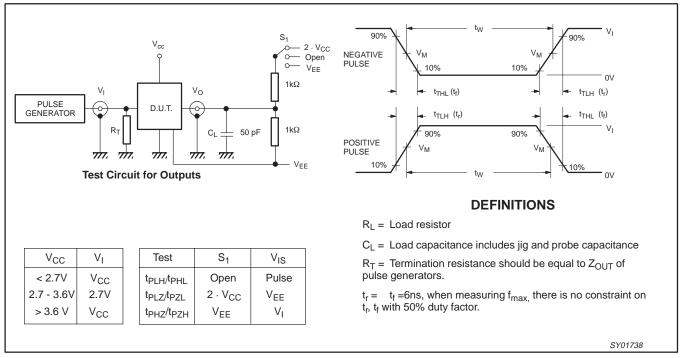
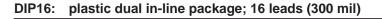
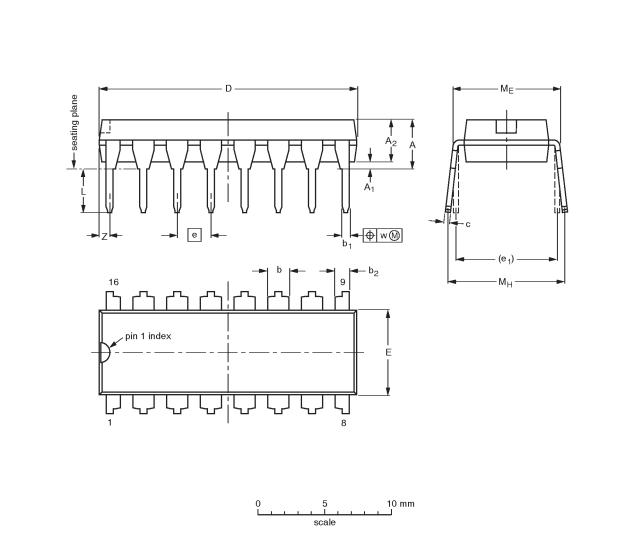


Figure 15. Load circuitry for switching times.

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DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	c	D ⁽¹⁾	E ⁽¹⁾	e	e ₁	L	M _E	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.030

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT38-4						-92-11-17- 95-01-14	

SOT38-4

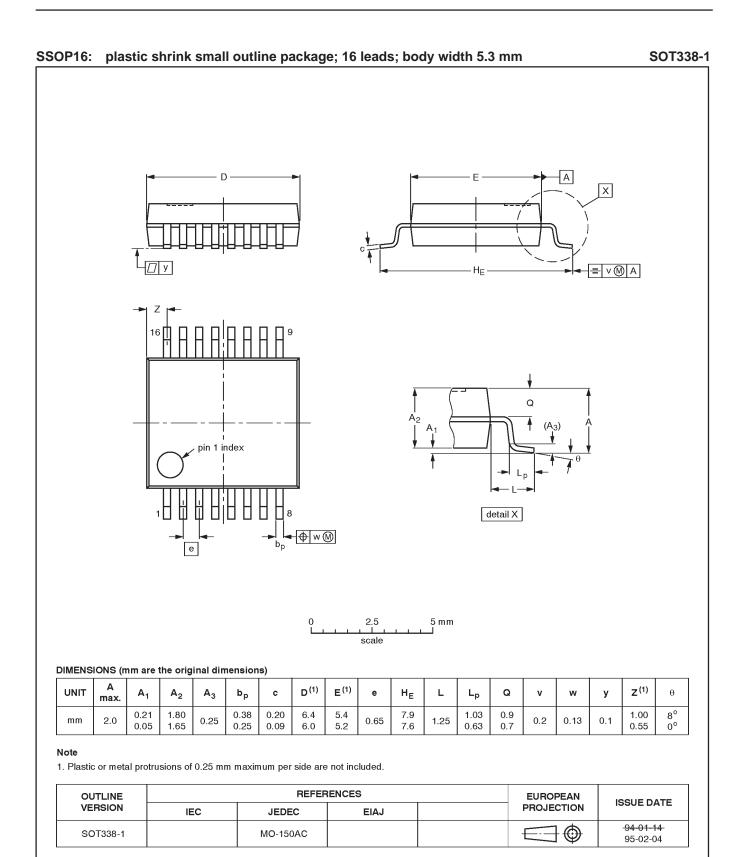
А X Πу = v 🕅 A ΗF Q A_2 A₁ pin 1 index Ā Lp H Ш 8 J<mark>bp</sub>₩M</mark> е detail X 2.5 5 m m 0 scale DIMENSIONS (inch dimensions are derived from the original mm dimensions) А E⁽¹⁾ Z⁽¹⁾ D⁽¹⁾ UNIT **A**₁ A_2 A_3 bp с е H_E L Lp Q ۷ w у θ max. 0.25 1.45 0.49 0.25 10.0 4.0 6.2 0.7 1.0 0.7 1.75 1.27 1.05 0.25 0.25 mm 0.25 0.1 0.10 1.25 0.36 0.19 9.8 3.8 5.8 0.4 0.6 0.3 8° 0° 0.0098 0.057 0.019 0.0098 0.39 0.16 0.24 0.039 0.028 0.028 inches 0.069 0.01 0.050 0.041 0.01 0.01 0.004 0.0039 0.049 0.014 0.0075 0.38 0.15 0.23 0.016 0.020 0.012 Note 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included. REFERENCES OUTLINE EUROPEAN ISSUE DATE VERSION PROJECTION IEC JEDEC EIAJ 91-08-13] 🔘 SOT109-1 076E07S MS-012AC E 95-01-23

SO16: plastic small outline package; 16 leads; body width 3.9 mm

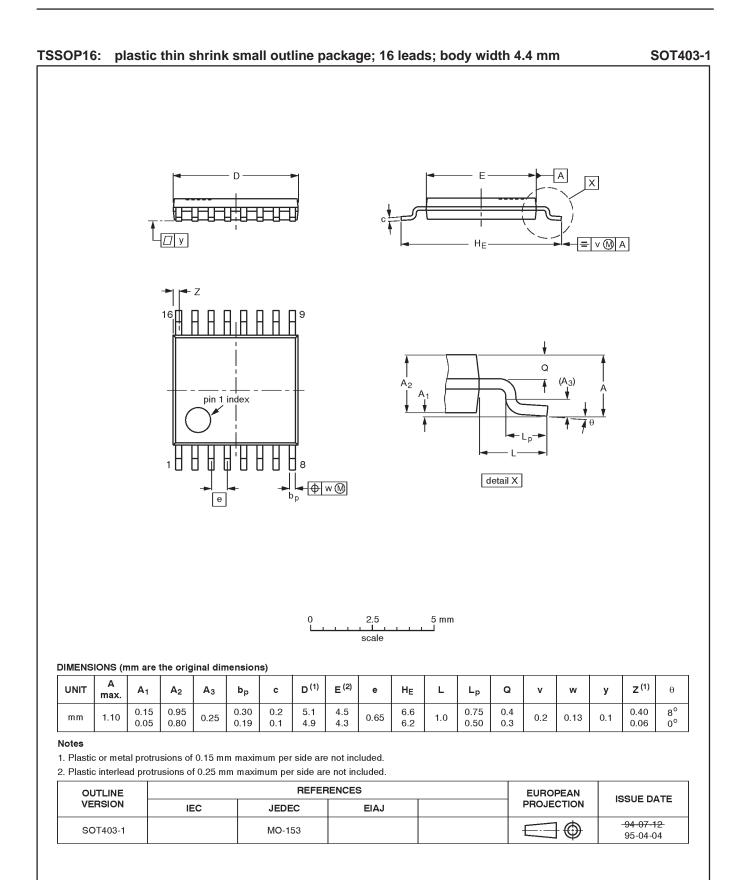
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DEFINITIONS					
Data Sheet Identification	Product Status	Definition			
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.			
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